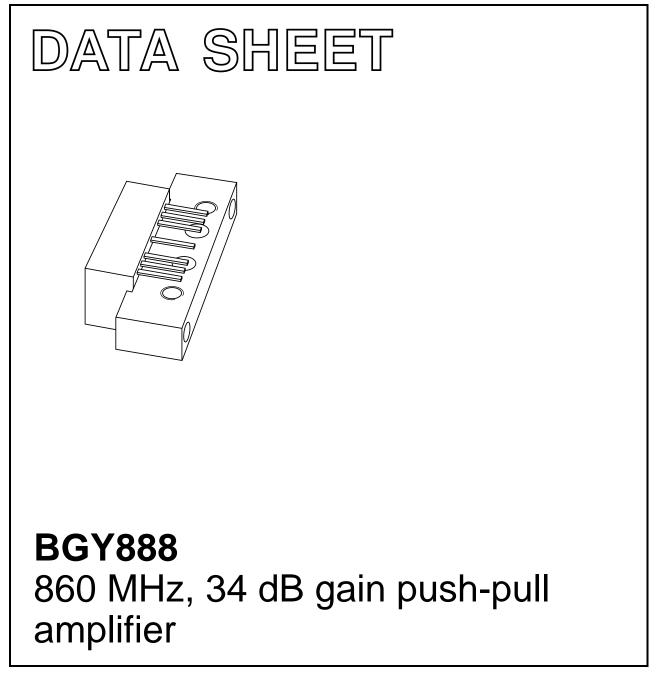
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Mar 30 2001 Oct 25



### FEATURES

- Excellent linearity
- Extremely low noise
- High gain
- Excellent return loss properties.

### APPLICATIONS

• Single module line extender in CATV systems operating over a frequency range of 40 to 860 MHz.

### DESCRIPTION

Hybrid high dynamic range amplifier module operating with a voltage supply of 24 V in a SOT115J package. The high gain module consists of two cascaded stages both in cascode configuration.

# PINNING SOT115J

PIN	DESCRIPTION
1	input
2, 3	common
5	+V <sub>B</sub>
7, 8	common
9	output

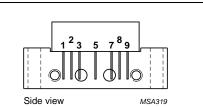


Fig.1 Simplified outline.

### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33.5	34.5	dB
		f = 860 MHz	34	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	340	mA

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage		55	dBmV
T <sub>stg</sub>	storage temperature		+100	°C
T <sub>mb</sub>	operating mounting base temperature		+100	°C

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### CHARACTERISTICS

**Table 1** Bandwidth 40 to 860 MHz;  $V_B = 24 V$ ;  $T_{case} = 30 °C$ ;  $Z_S = Z_L = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33.5	34	34.5	dB
		f = 860 MHz	34	35	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	1.1	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.2	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	25	_	dB
		f = 80 to 160 MHz	18.5	28	-	dB
		f = 160 to 320 MHz	17	28	_	dB
		f = 320 to 640 MHz	15.5	21	_	dB
		f = 640 to 860 MHz	14	18.5	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	25.5	_	dB
		f = 80 to 160 MHz	18.5	28.5	_	dB
		f = 160 to 320 MHz	17	26.5	_	dB
		f = 320 to 640 MHz	15.5	20.5	_	dB
		f = 640 to 860 MHz	14	21	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	-	225	deg
СТВ	composite triple beat	49 channels flat; $V_o = 44 \text{ dBmV}$ ; measured at 859.25 MHz	-	-63.5	-60	dB
X <sub>mod</sub>	cross modulation	49 channels flat; $V_o = 44 \text{ dBmV}$ ; measured at 55.25 MHz	_	-63	-59	dB
CSO	composite second order distortion	49 channels flat; $V_o = 44 \text{ dBmV}$ ; measured at 860.5 MHz	_	-64	-55	dB
d <sub>2</sub>	second order distortion	note 1	_	-74	-65	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	58	60	_	dBmV
F	noise figure	f = 50 MHz	_	4	4.5	dB
		f = 550 MHz	_	_	5	dB
		f = 600 MHz	-	-	5	dB
		f = 650 MHz	_	-	5.5	dB
		f = 750 MHz	_	-	6	dB
		f = 860 MHz	_	5.5	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	325	340	mA

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$  $f_q = 805.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 860.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:  $f_p = 851.25 \text{ MHz}; V_p = V_0;$   $f_q = 858.25 \text{ MHz}; V_q = V_0-6 \text{ dB};$   $f_r = 860.25 \text{ MHz}; V_r = V_0-6 \text{ dB};$ measured at  $f_p + f_q - f_r = 849.25 \text{ MHz}.$
- 3. The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 30 V.

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33.5	34	34.5	dB
		f = 860 MHz	34	35	-	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	1.1	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.2	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	25	-	dB
		f = 80 to 160 MHz	18.5	28	-	dB
		f = 160 to 320 MHz	17	28	-	dB
		f = 320 to 640 MHz	15.5	21	_	dB
		f = 640 to 860 MHz	14	18.5	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	25.5	-	dB
		f = 80 to 160 MHz	18.5	28.5	-	dB
		f = 160 to 320 MHz	17	26.5	-	dB
		f = 320 to 640 MHz	15.5	20.5	_	dB
		f = 640 to 860 MHz	14	21	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	-	225	deg
СТВ	composite triple beat	129 channels flat; $V_o = 44 \text{ dBmV}$ ; measured at 859.25 MHz	-	-47.5	-46	dB
X <sub>mod</sub>	cross modulation	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-53.5	-50	dB
CSO	composite second order distortion	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz	-	-56	-48	dB
d <sub>2</sub>	second order distortion	note 1	_	-74	-65	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	58	60	_	dBmV
F	noise figure	see Table 1	_	_	_	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	325	340	mA

### Table 2 Bandwidth 40 to 860 MHz; $V_B$ = 24 V; $T_{case}$ = 30 °C; $Z_S$ = $Z_L$ = 75 $\Omega$

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$  $f_q = 805.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 860.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:
- $\begin{array}{l} f_{p}=851.25 \text{ MHz}; \text{ } V_{p}=\text{V}_{0}; \\ f_{q}=858.25 \text{ MHz}; \text{ } V_{q}=\text{V}_{o}-6 \text{ } d\text{B}; \\ f_{r}=860.25 \text{ } \text{MHz}; \text{ } V_{r}=\text{V}_{o}-6 \text{ } d\text{B}; \\ \text{measured at } f_{p}+f_{q}-f_{r}=849.25 \text{ } \text{MHz}. \end{array}$
- 3. The module normally operates at  $V_B$  = 24 V, but is able to withstand supply transients up to 30 V.

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33.5	34	34.5	dB
		f = 750 MHz	34	-	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	-	2.2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	—	±0.45	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	25	-	dB
		f = 80 to 160 MHz	18.5	28	-	dB
		f = 160 to 320 MHz	17	28	-	dB
		f = 320 to 640 MHz	15.5	21	-	dB
		f = 640 to 750 MHz	14	18.5	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	25.5	-	dB
		f = 80 to 160 MHz	18.5	28.5	-	dB
		f = 160 to 320 MHz	17	26.5	-	dB
		f = 320 to 640 MHz	15.5	20.5	-	dB
		f = 640 to 750 MHz	14	21	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	-	225	deg
СТВ	composite triple beat	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	-52.5	-50	dB
X <sub>mod</sub>	cross modulation	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-55.5	-51	dB
CSO	composite second order distortion	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz	-	-61.5	-53	dB
d <sub>2</sub>	second order distortion	note 1	_	-	-65	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	59	—	_	dBmV
F	noise figure	see Table 1	_	—	_	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	325	340	mA

### Table 3 Bandwidth 40 to 750 MHz; $V_B$ = 24 V; $T_{case}$ = 30 °C; $Z_S$ = $Z_L$ = 75 $\Omega$

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$  $f_q = 691.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 746.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:
- 3. The module normally operates at  $V_B$  = 24 V, but is able to withstand supply transients up to 30 V.

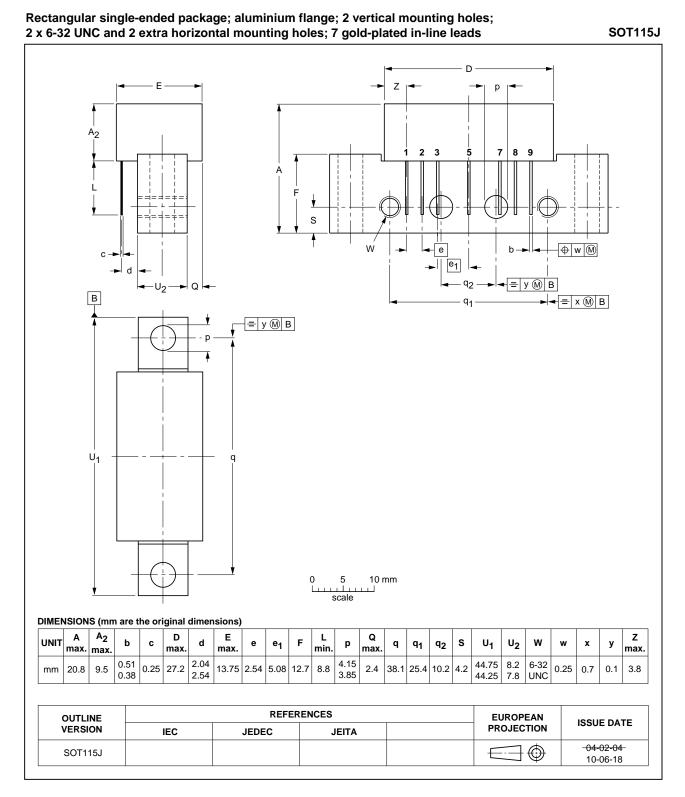
### BGY888

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33.5	34	34.5	dB
		f = 600 MHz	34	-	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	-	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	-	±0.35	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	25	-	dB
		f = 80 to 160 MHz	18.5	28	-	dB
		f = 160 to 320 MHz	17	28	-	dB
		f = 320 to 600 MHz	16	21	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	25.5	-	dB
		f = 80 to 160 MHz	18.5	28.5	-	dB
		f = 160 to 320 MHz	17	26.5	-	dB
		f = 320 to 600 MHz	16	20.5	-	dB
S <sub>21</sub>	phase response	f = 50MHz	135	-	225	deg
СТВ	composite triple beat	85 channels flat; $V_0 = 44 \text{ dBmV}$ ; measured at 595.25 MHz	-	-56.5	-55	dB
X <sub>mod</sub>	cross modulation	85 channels flat; $V_o = 44 \text{ dBmV}$ ; measured at 55.25 MHz	_	-58	-54	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-69.5	-56	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-68	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61	_	_	dBmV
F	noise figure (DC)	see Table 1	-	-	-	dB
I <sub>tot</sub>	total current consumption	note 3	_	325	340	mA

### **Table 4** Bandwidth 40 to 600 MHz; $V_B = 24 V$ ; $T_{case} = 30 °C$ ; $Z_S = Z_L = 75 \Omega$

- $\begin{array}{ll} \mbox{1.} & f_p = 55.25 \mbox{ MHz}; \mbox{ V}_p = 44 \mbox{ dBmV}; \\ f_q = 541.25 \mbox{ MHz}; \mbox{ V}_q = 44 \mbox{ dBmV}; \\ \mbox{ measured at } f_p + f_q = 596.5 \mbox{ MHz}. \end{array}$
- 2. Measured according to DIN45004B:  $f_p = 590.25 \text{ MHz}; V_p = V_0;$   $f_q = 597.25 \text{ MHz}; V_q = V_0 -6 \text{ dB};$   $f_r = 599.25 \text{ MHz}; V_r = V_0 -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 588.25 \text{ MHz}.$
- 3. The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 30 V.

### PACKAGE OUTLINE



**BGY888** 

### **BGY888**

### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION	
Objective data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.	
Product data sheet	Production	This document contains the product specification.	

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#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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